

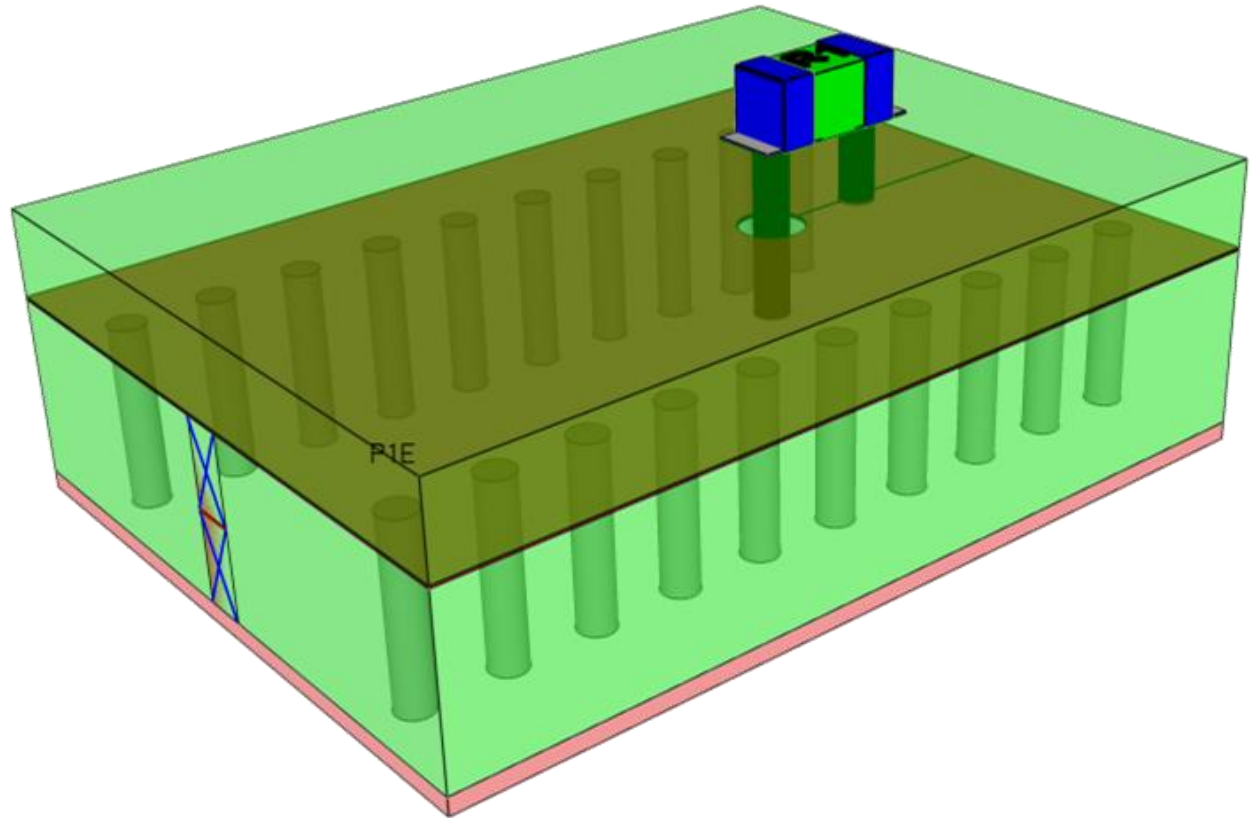
# EMPIRE XPU Tutorial

## LTCC Transition



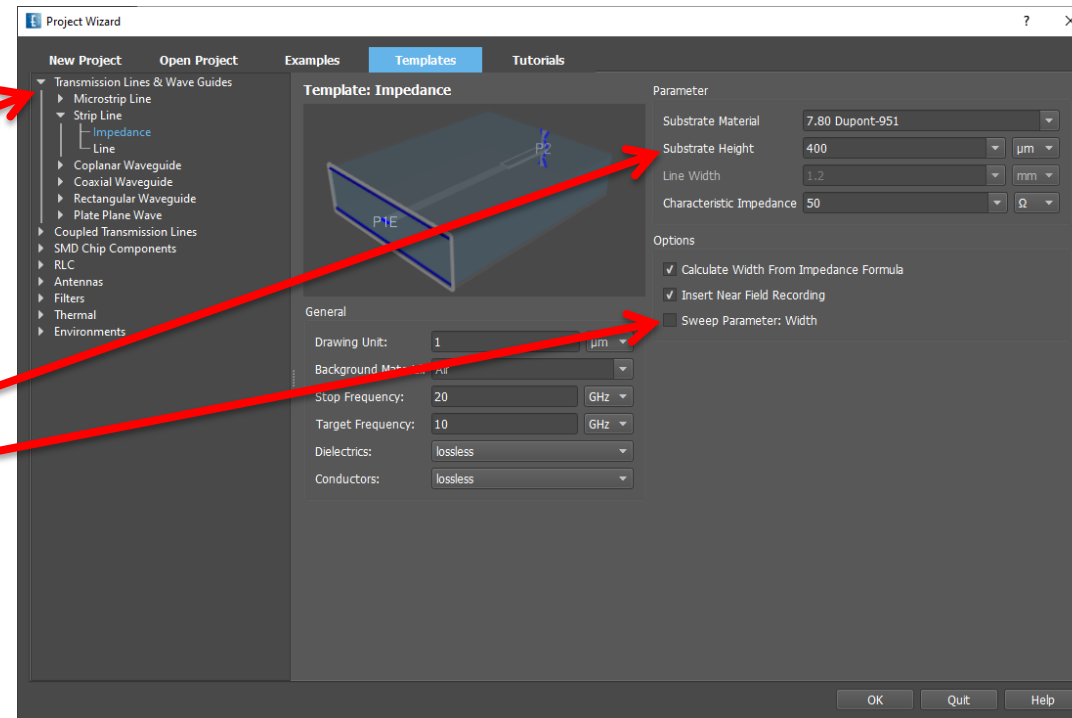
# Overview: Topics

- Template Wizard
- Simulation
- Insert SMD Resistor
- Parameter Sweep
- Via Fence



# Step 1: Stripline in Dupont 951

- Start Empire XPU
- Select Templates → Transmission...  
→ Strip Line → Impedance
- Keep Substrate Material  
7.8 Dupont-951
- Set „Substrate Height“ to 400  $\mu\text{m}$
- Uncheck „Sweep Parameter: Width“
- Click OK
- Select “File -> Save As”
- Select folder and enter name, e.g.  
Trans.emx



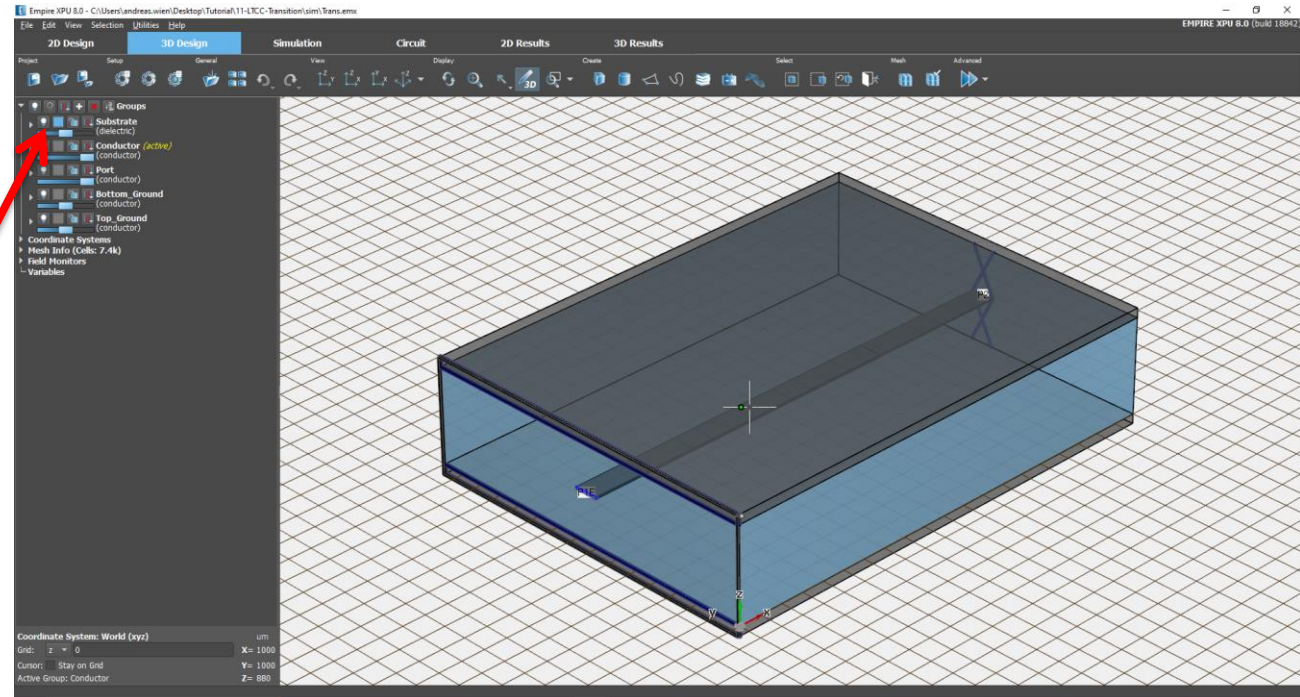
## Comments:

Using the template “Strip line...”

- Automatic generation of Dielectric, port and mesh
- QTEM port at start, absorbing port at end
- 50 Ohm line, designed by formula

# Step 2: Structure Check

- Check the model
- Increase transparency of groups
- Optionally recolor groups
- Open groups to verify heights and properties

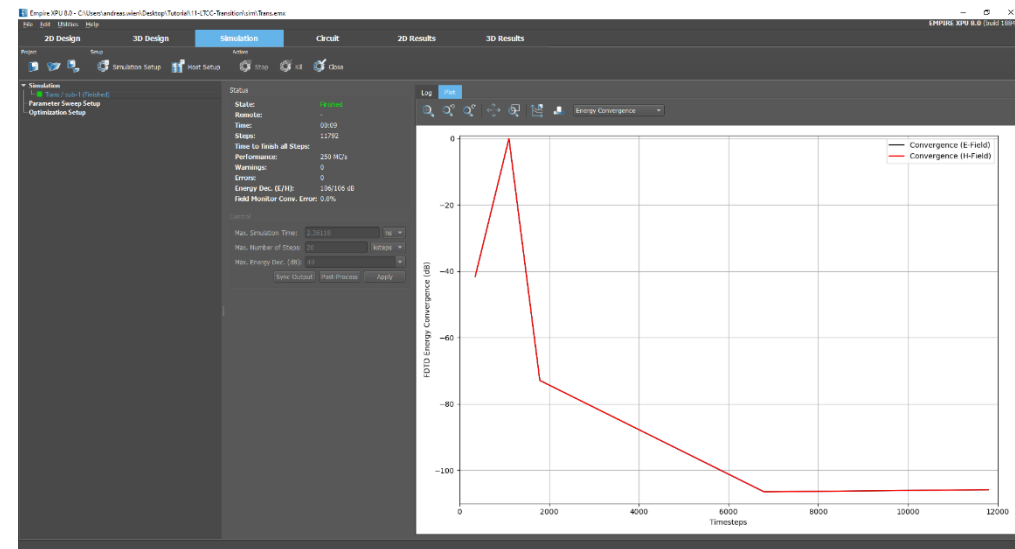
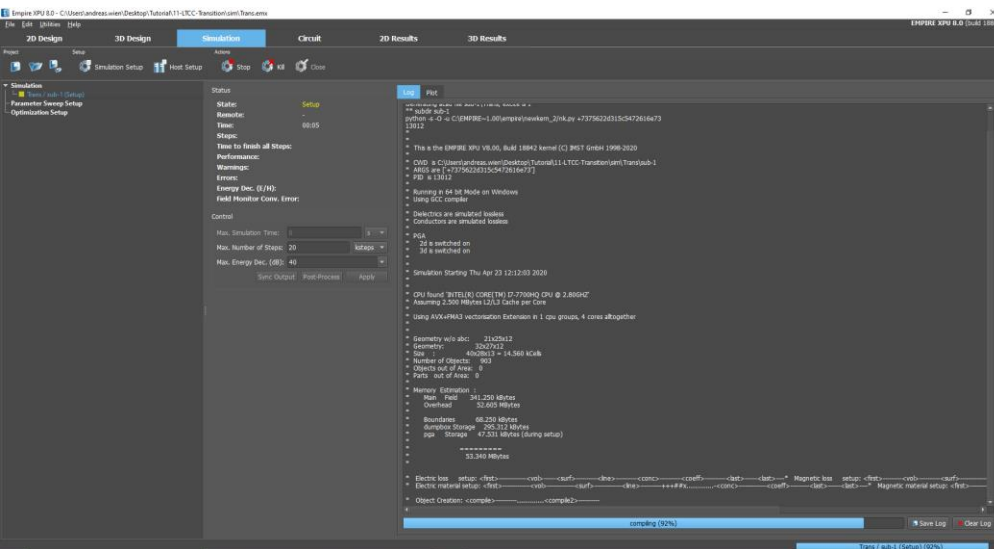


# Step 3: Stripline Simulation

- Click “Start Simulation”  → “OK”

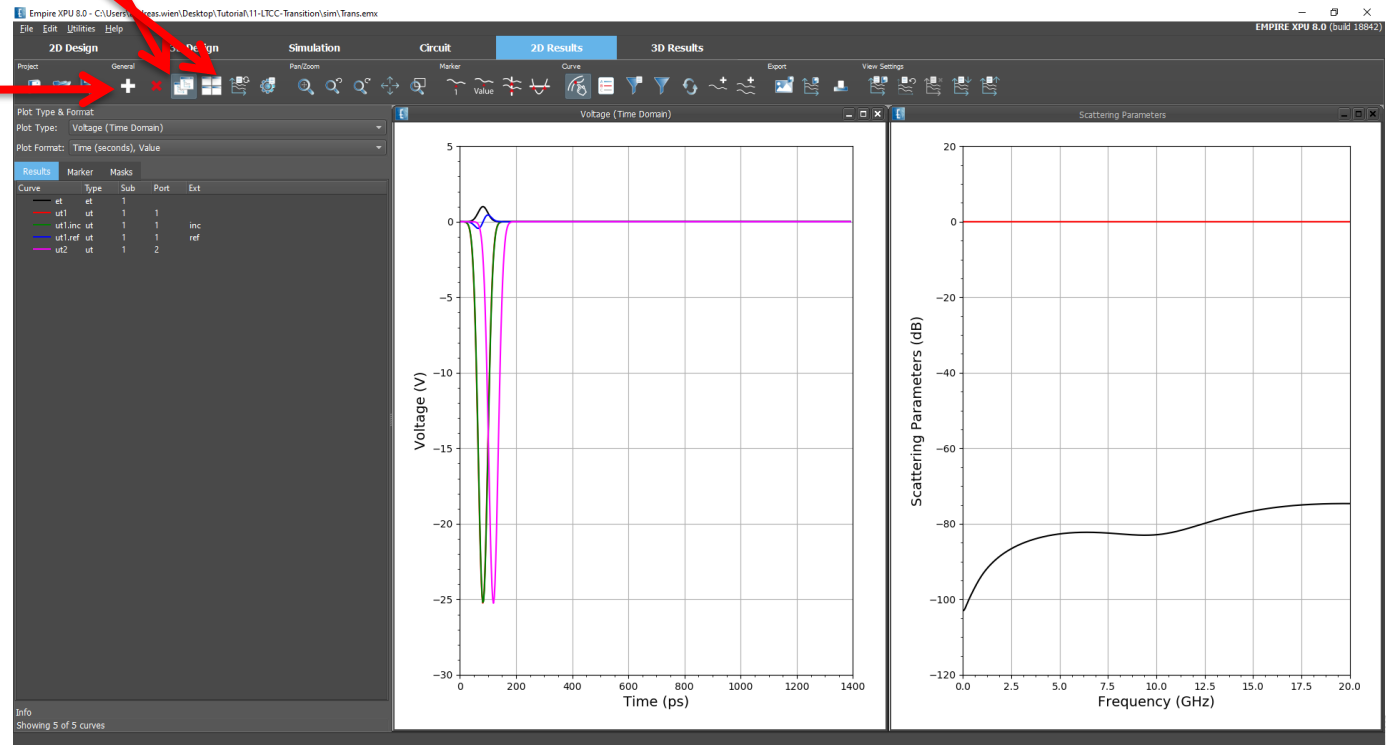
Log Tab: Compilation progress

Plot Tab: Energy vs. Timesteps




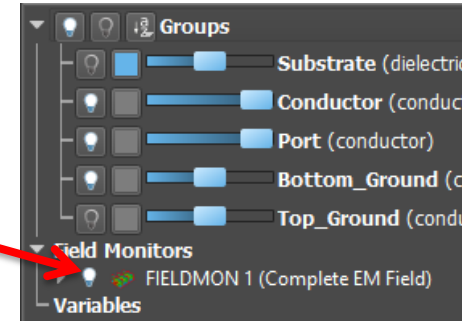
# Step 4: 2D Postprocessing Results

- Switch to “2D Results” tab. Plot Type: Scattering Parameters
- Click General: Add Result. Change Plot Type to: Voltage (Time Domain)
- Click Toggle View Mode.
- Click Tile Sub Windows

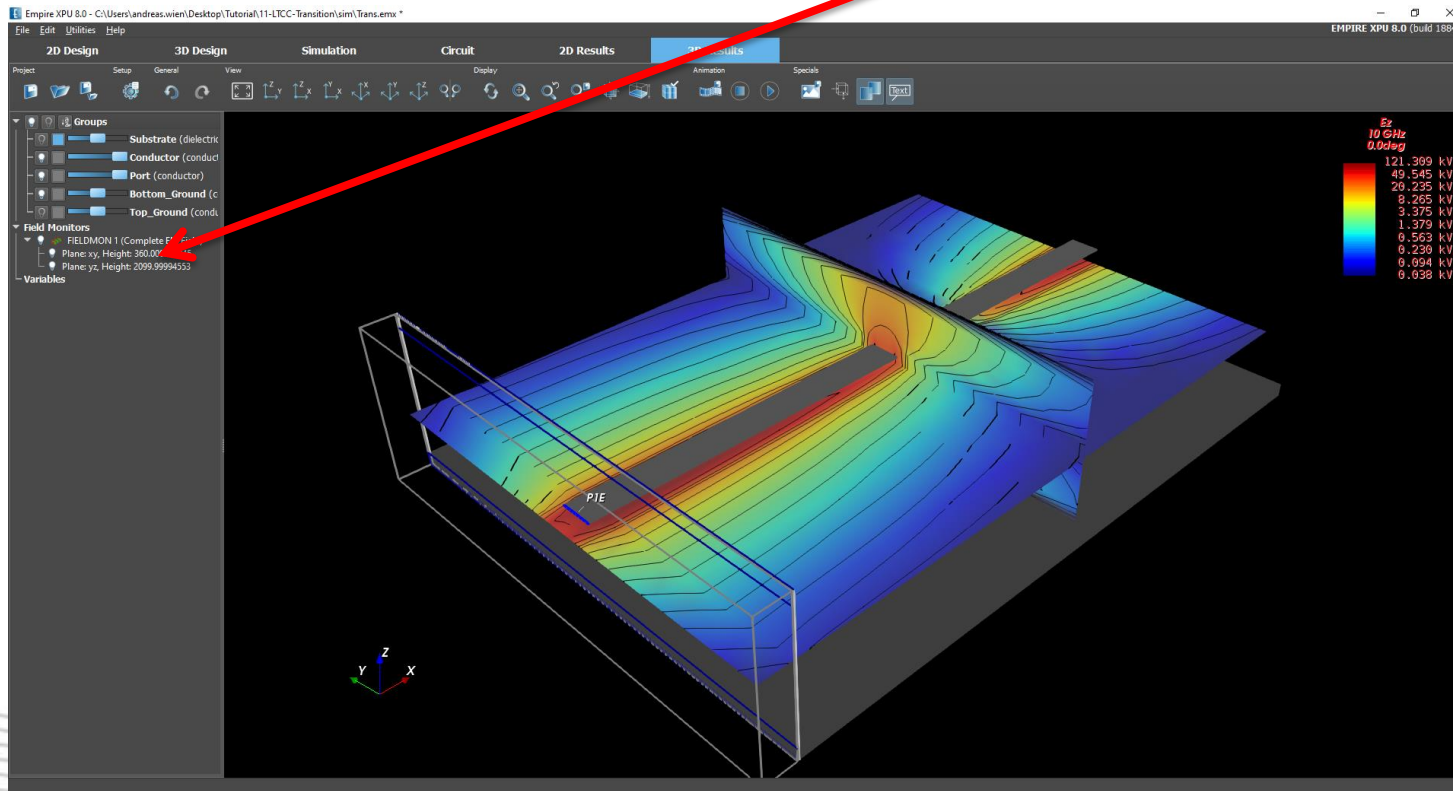


# Step 5: Near Field




- Switch to „3D Results“ tab, Click „Iso z View“ 
- Open Field Monitors – Switch On FIELDMON 1
- Turn off visibility of Top\_Ground and Substrate groups

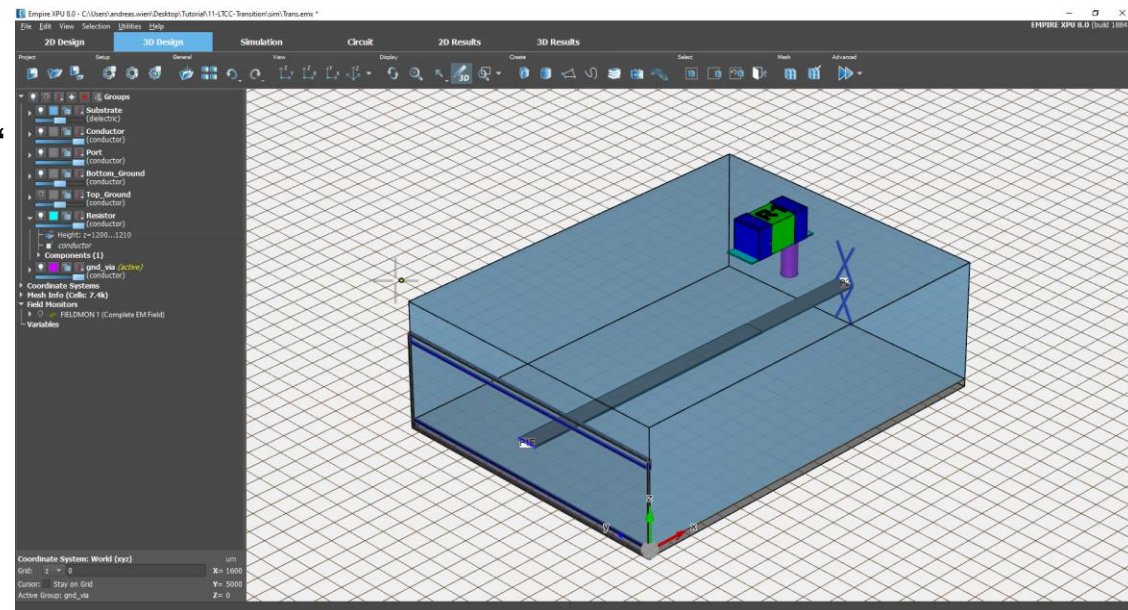


*Hint: Move field monitor planes to adjust the field display planes (double click on plane height to adjust the height)*



# Step 6: Insert SMD Resistor

- Go back to „3D Design“ Tab – Iso Z View, Switch off Field Monitor
- Open group Substrate, turn on group
- Double click „Height“, set 0...1200, confirm „Assign new height ...“
- Click „Add Group“ , enter Resistor
- Set height 1200...1210
- Click „Create Library Object“ 
- Tab: „SMD“ → Click „SMD Resistor“
- Left click at Point: x=3000, y=1500
- Click „Edit Settings“
- Set size SMD0201, Press Ok (2x)
- Click „Add Group“, enter „gnd-via“
- Hide group: Resistor, zoom in
- Click „Create Cylinder“, 
- Click at Point : x=3250, y=1500
- Press Tab and define:
  - height z: 800 ... 1200
  - radius r=80
- OK

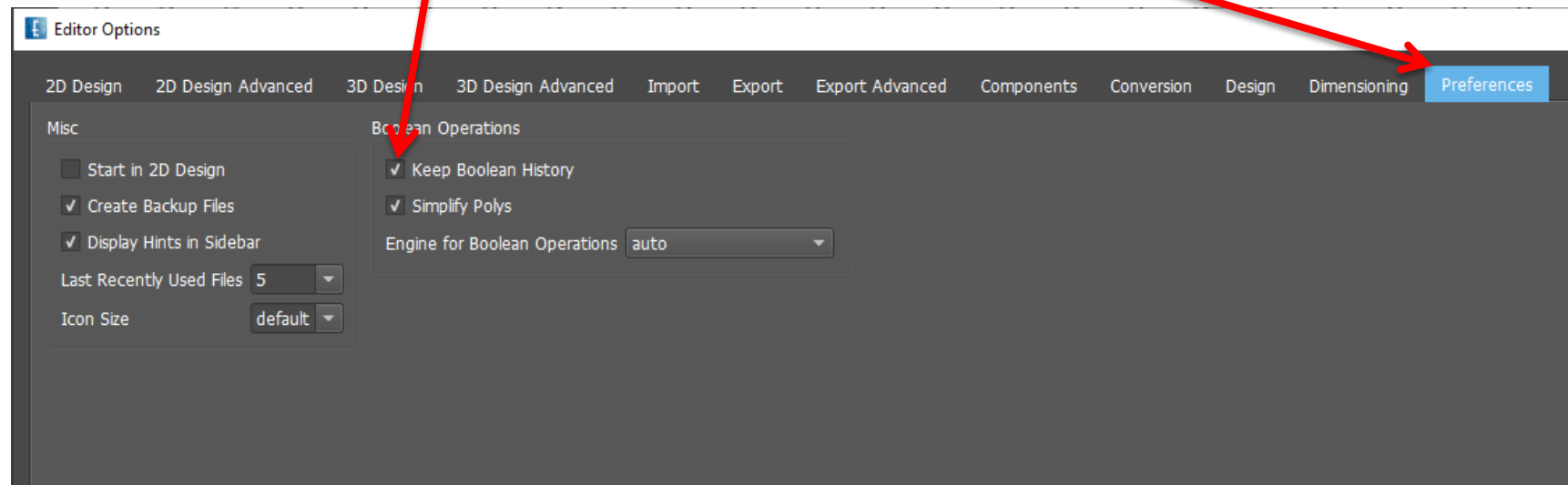
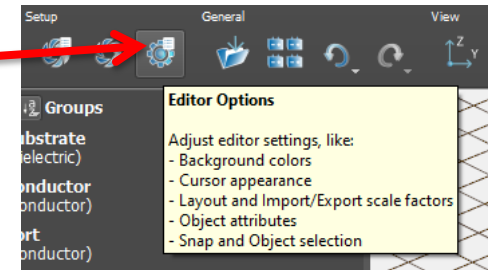









# Step 7: Boolean History

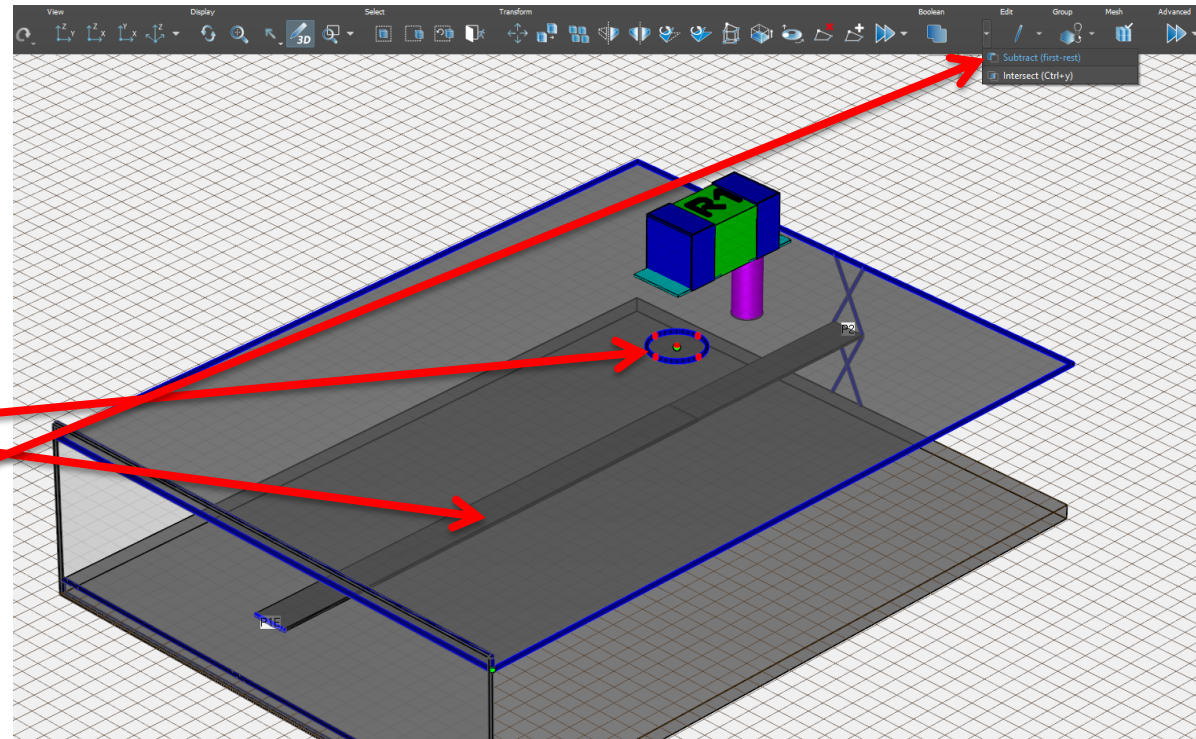
For the next steps we need Boolean History to define a parametric hole

- Go to “Editor Options“
- Switch to “Preferences“ tab
- Check box “Keep Boolean History“
- OK



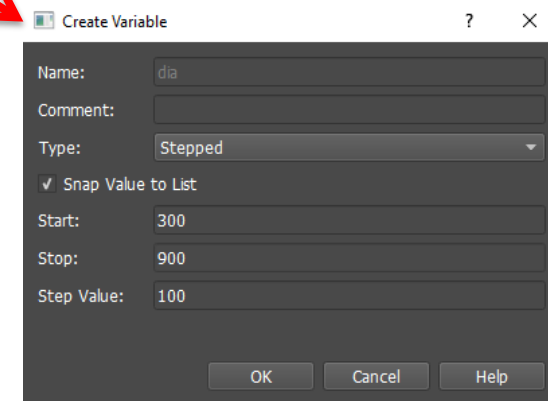
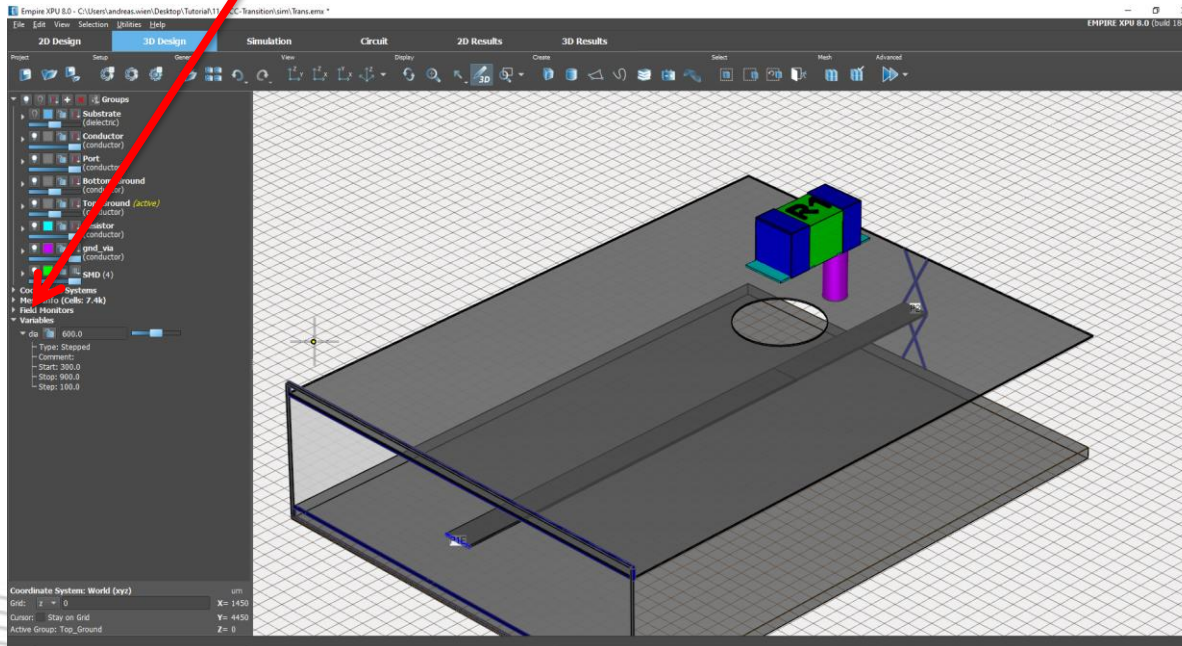
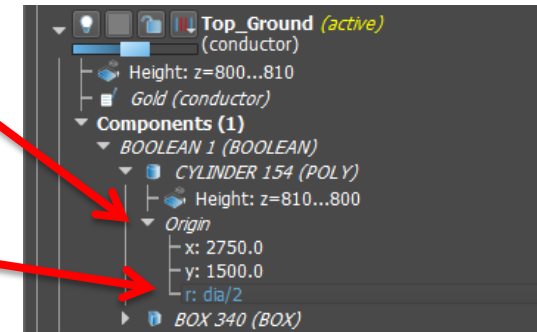
# Step 7: Hole creation

- Hide group „Substrate“
- Switch on group „Top\_Ground“
- Right click on group name, select „Set Active“
- Open group, double click „Height“, set 800...810, confirm Yes
- Click „Create Cylinder“, 
- Click Point :  $x=2750$ ,  $y=1500$ ,  $r=150$
- Set height to  $dw= -10$ , OK
- Click the plane 
- Click the cylinder 
- In Boolean Menu click 
- Select Subtract (first-rest) 














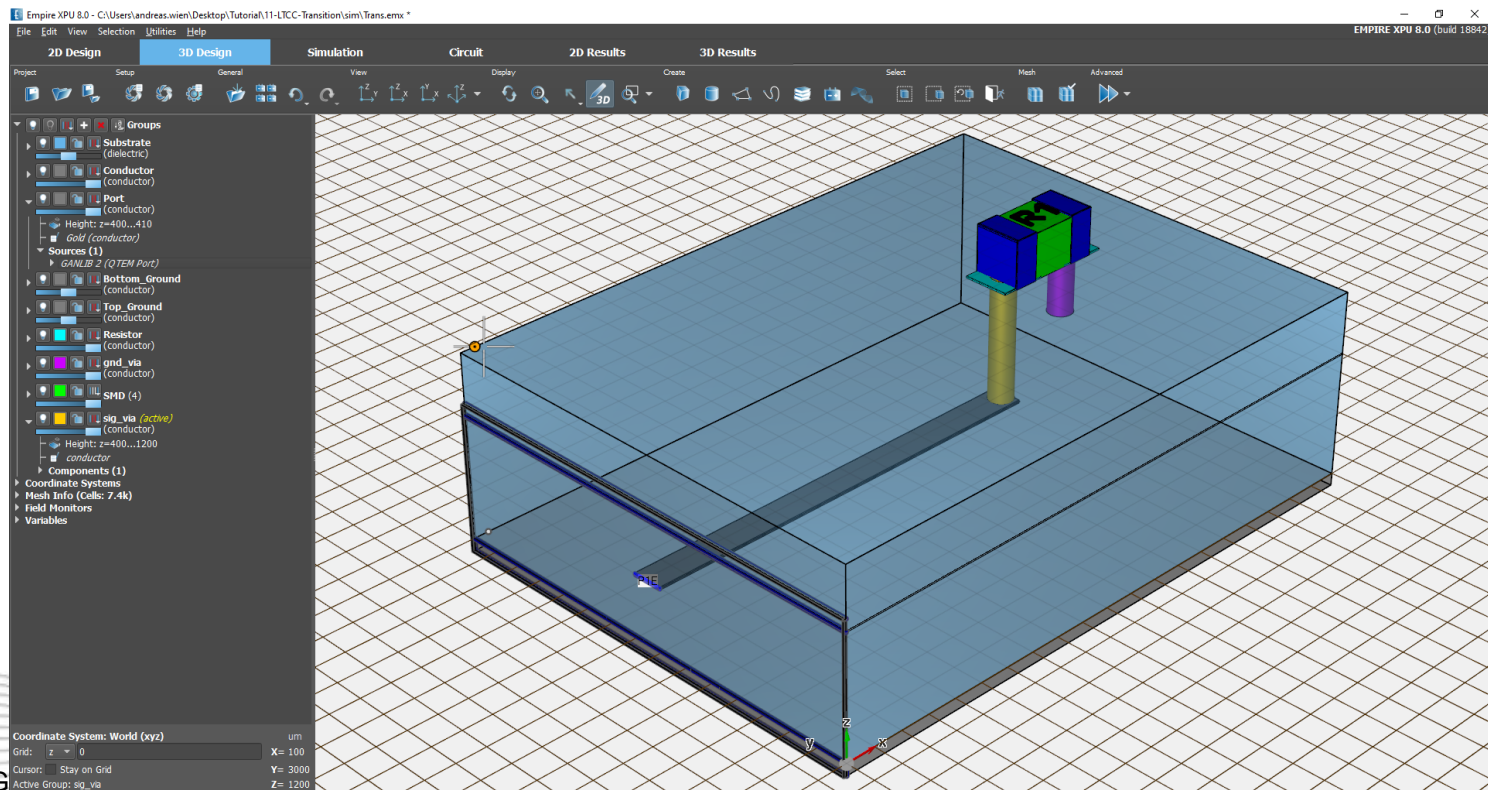
# Step 8: Parametric Hole

- In Group „Top\_Ground“ open Components – BOOLEAN – Poly - Origin
- Double click „r“, Enter: dia/2
- Set Type: Stepped, Start 300, Stop 900, Step 100, OK
- Check Variable range in side menu





# Step 9: Adjust Model, Via Hole

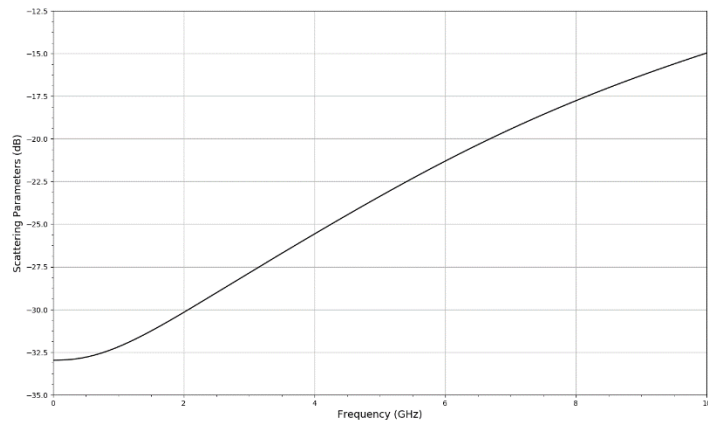
- Create group „sig-via“, set height 400...1200
- Show groups: Conductor & sig-via
- „Create Cylinder“ 
- Click Point:  $x=2750$ ,  $y=1500$ ,  $r=80$ , long click for group height, OK
- Unhide all groups          Groups
- Open Group Ports, open Sources, Click GANLIB 1 (Stripline), Click „Delete“ 



# Step 10: Simulation Setup

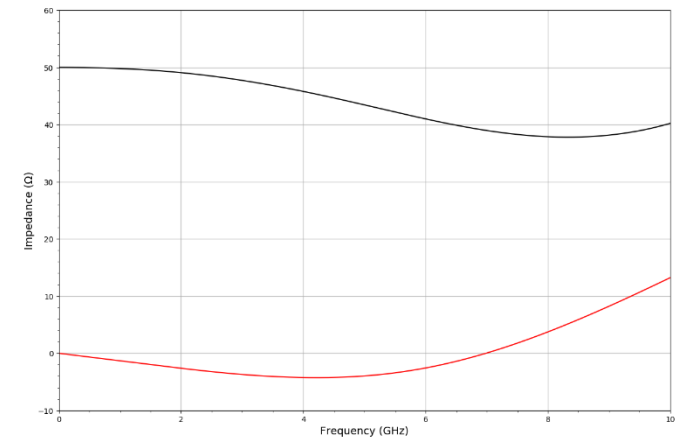
- Open „Simulation Setup“  , select „EM Setup“ Tab
- Set „Stop Frequency“ = 10GHz
- Select „Boundary“ Tab
- „Boundary Conditions“ y<sub>min</sub>=Electric, y<sub>max</sub>=Electric
- „Boundary Distance“ → Set z<sub>max</sub> = 500, OK
- Click „Start Simulation“  , OK, wait for finish
- Select „2D Results“ Tab, Select Plot Type Scattering Parameters, Impedance

S11



20 dB Matching up to 6.5 GHz (dia=300)

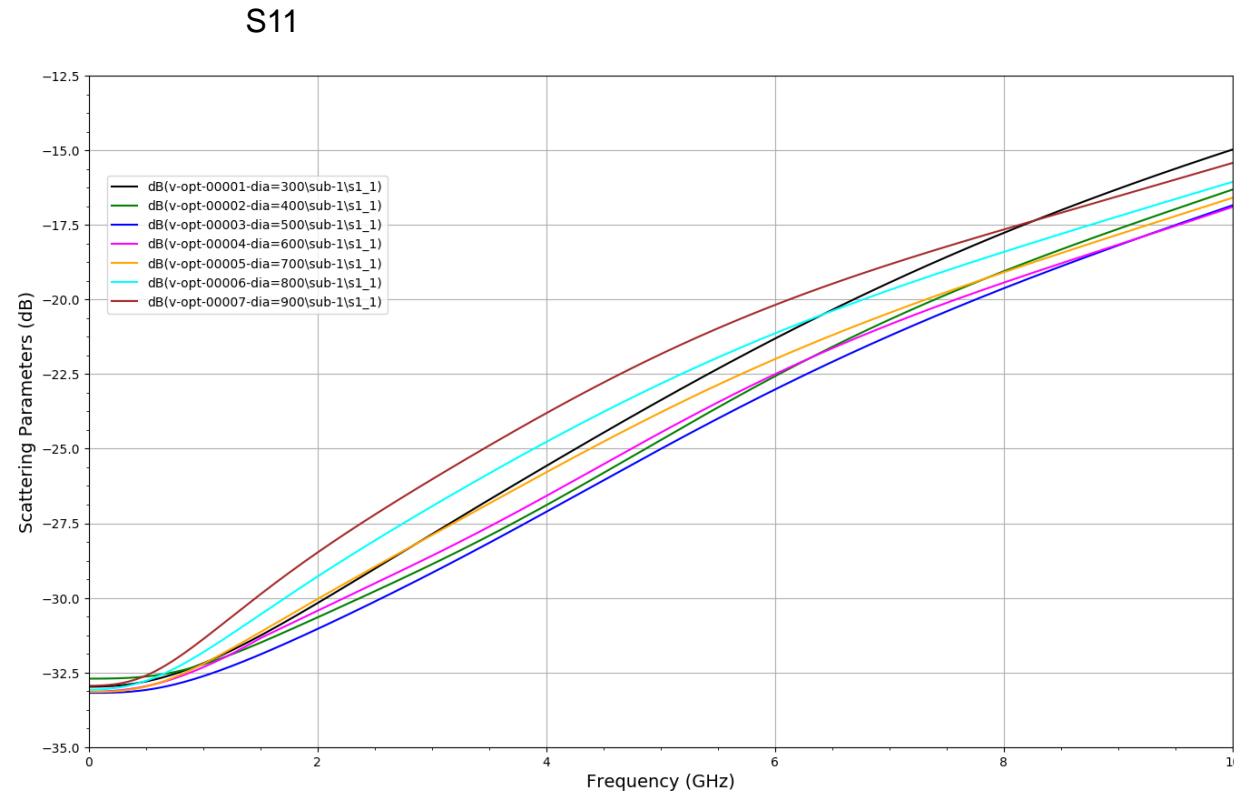
Impedance Z1.in



Capacitive for low frequencies





# Step 11: Diameter Variation

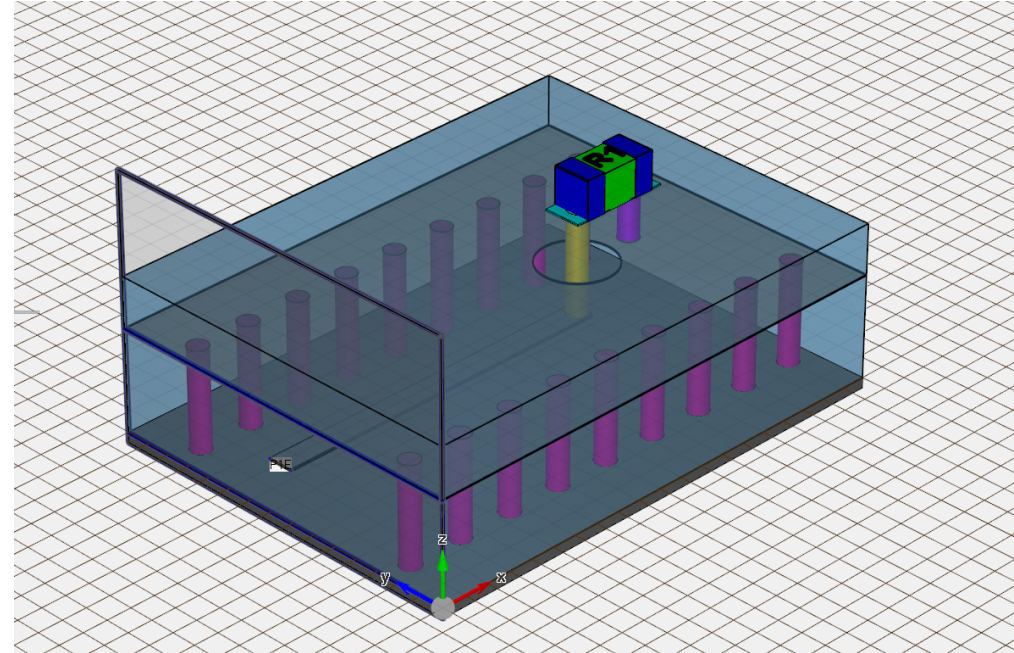
- Select “Simulation“ Tab
- Click „Parameter Sweep Setup“
- Click „Create Parameter Sweep“
- Click „Start“, confirm
- Wait for Sweep to finish
- Select „2D Results“ Tab
- Plot Type: S-Parameters
- Select all Curves – right click – Show all



20 dB Matching up to 7.8 GHz with dia=500

# Step 12: Via Fence

- Select „3D Design“ tab
  - Create group „fence“, height 0...800
  - Click „Create Library Object“ 
  - Tab : „Layout“ → „Viafence“ 
  - Click at x=0, y=500, (z=810)
  - Click at x=4000, y=500
  - Long click to finish and use group height
  - Click „Edit Settings“
  - Set: D1=160, D2=160, dist=450, 2x OK
- 
- Right click on group „fence“, „Select group objects“
  - Click „Copy & Mirror“ 
  - Enter Start X=0, Y=1500 Stop X=10, Y=1500, OK
- 
- Click „Simulation Setup“  → Boundary Tab
  - Change „Boundary Conditions“: ymin = ymax = Absorbing Sheet, OK
  - Click „Start Simulation“, OK



# Step 13: Animation

- „3D Results“ Tab, Switch on Field Monitor, Right click Edit, Use Optimization = Off, OK
- Switch off groups Substrate, Top\_ground
- Monitor Planes  $xz=1500$ ,  $xy=280$

